## isc N-Channel MOSFET Transistor

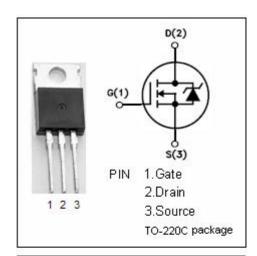
14N05

### • FEATURES

- Drain Current I<sub>D</sub>= 14A@ T<sub>C</sub>=25℃
- · Drain Source Voltage-
  - : V<sub>DSS</sub>= 50V(Min)
- Static Drain-Source On-Resistance
  - :  $R_{DS(on)} = 0.1 \Omega (Max)$
- · Fast Switching

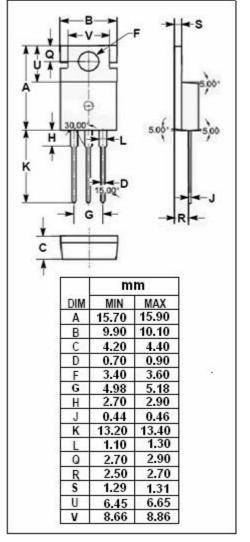
#### APPLICATIONS

- · Switch regulators
- · Switching converters motor drivers and relay drivers



## • ABSOLUTE MAXIMUM RATINGS(T<sub>a</sub>=25°C)

SYMBOL	PARAMETER	VALUE	UNIT
$V_{DSS}$	Drain-Source Voltage	50	V
$V_{GS}$	Gate-Source Voltage-Continuous	±10	٧
I <sub>D</sub>	Drain Current-Continuous	14	А
P <sub>D</sub>	Total Dissipation @T <sub>C</sub> =25℃	48	W
T <sub>j</sub>	Max. Operating Junction Temperature	150	$^{\circ}$
T <sub>stg</sub>	Storage Temperature -59		$^{\circ}$



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# isc N-Channel MOSFET Transistor

14N05

## • ELECTRICAL CHARACTERISTICS

T<sub>C</sub>=25℃ unless otherwise specified

SYMBOL	PARAMETER	CONDITIONS	MIN	TYPE	MAX	UNIT
$V_{(BR)DSS}$	Drain-Source Breakdown Voltage	V <sub>GS</sub> = 0; I <sub>D</sub> =250μA	50			V
V <sub>GS(th)</sub>	Gate Threshold Voltage	V <sub>DS</sub> = V <sub>GS</sub> ; I <sub>D</sub> =250μA	2.0		4.0	V
$V_{SD}$	Diode Forward On-voltage	I <sub>S</sub> = 14A;V <sub>GS</sub> = 0			1.5	V
R <sub>DS(on)</sub>	Drain-Source On-Resistance	V <sub>GS</sub> = 10V; I <sub>D</sub> = 14A			0.1	Ω
I <sub>GSS</sub>	Gate-Body Leakage Current	V <sub>GS</sub> = ±10V;V <sub>DS</sub> = 0			±100	nA
I <sub>DSS</sub>	Zero Gate Voltage Drain Current	V <sub>DS</sub> =40V; V <sub>GS</sub> = 0			1	μA
C <sub>iss</sub>	Input Capacitance	V <sub>DS</sub> =25V;		670		
$C_{rss}$	Reverse Transfer capacitance	V <sub>GS</sub> =0V;		50		pF
C <sub>oss</sub>	Output Capacitance	f <sub>T</sub> =1MHz		185		
t <sub>r</sub>	Rise Time	V <sub>GS</sub> =10V;		24		
t <sub>d(on)</sub>	Turn-on Delay Time	$R_{GS}$ =0.6 $\Omega$		13		
t <sub>f</sub>	Fall Time	V <sub>DD</sub> =25V;		16		ns
t <sub>d(off)</sub>	Turn-off Delay Time	R <sub>L</sub> =3.57 Ω		42		

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